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NTE910 & NTE910D

Integrated Circuits

High-Speed Differential Comparator

Description:

The NTE910 (8-Lead Metal Can) and NTE910D (14-Lead DIP) are differential voltage comparators intended for applications requiring high accuracy and fast response times. The device is useful as a variable threshold Schmitt trigger, a pulse-height discriminator, a voltage comparator in high-speed A/D converters, a memory sense amplifier or a high noise immunity line receiver. The output of the comparator is compatible with all integrated logic forms.

Features:

- 5mV Maximum Offset Voltage
- 5 μ A Maximum Offset Current
- 1000 Minimum Voltage Gain
- 20 μ V/ $^{\circ}$ C Maximum Offset Voltage Drift

Absolute Maximum Ratings:

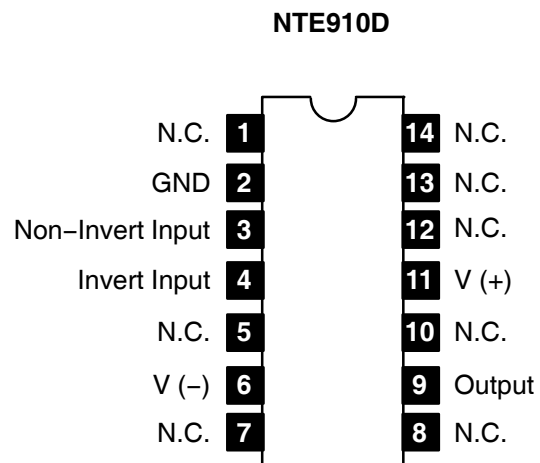
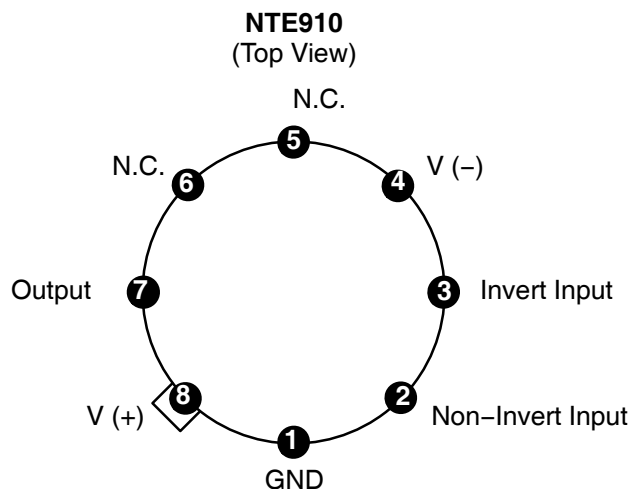
Positive Supply Voltage	$\pm 14\text{V}$
Negative Supply Voltage	-7V
Peak Output Current	10mA
Differential Input Voltage	$\pm 5\text{V}$
Input Voltage	$\pm 7\text{V}$
Power Dissipation ($T_A \leq +70^{\circ}\text{C}$)	
NTE910	500mW
Derate Linearly Above $+70^{\circ}\text{C}$	6.3mW/ $^{\circ}\text{C}$
NTE910D	670mW
Derate Linearly Above $+70^{\circ}\text{C}$	8.3mW/ $^{\circ}\text{C}$
Storage Temperature Range	
NTE910	-65° to $+150^{\circ}\text{C}$
NTE910D	-55° to $+125^{\circ}\text{C}$
Operating Temperature Range	0° to $+70^{\circ}\text{C}$
Lead Temperature (During Soldering)	
NTE910 (60sec)	$+300^{\circ}\text{C}$
NTE910D (10sec)	$+260^{\circ}\text{C}$

Electrical Characteristics: ($T_A = +25^{\circ}\text{C}$, $V_+ = 12\text{V}$, $V_- = -6\text{V}$ unless otherwise specified)

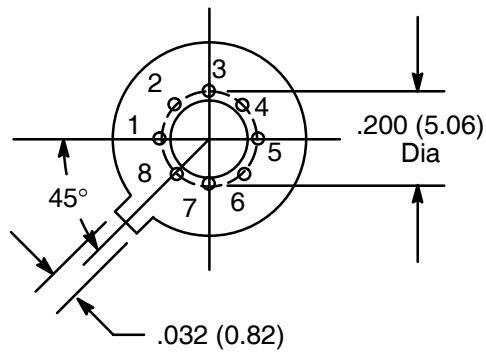
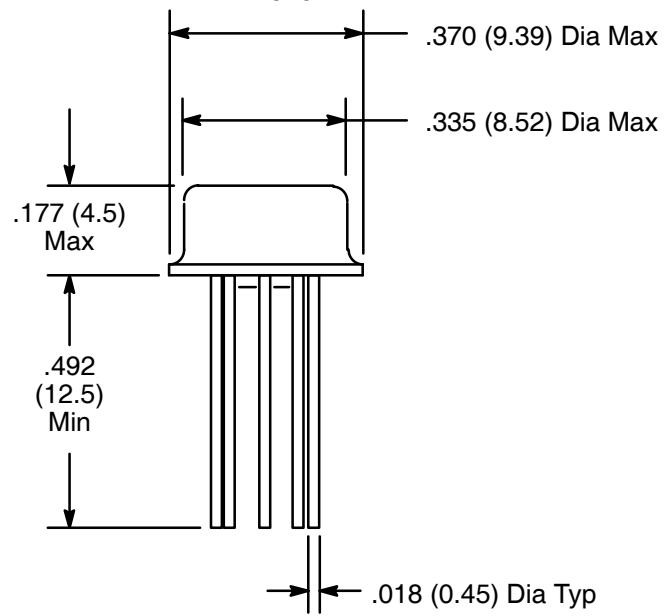
Parameter	Test Conditions (Note 1)		Min	Typ	Max	Unit
Input Offset Voltage	$R_A \leq 200\Omega$		–	1.6	5.0	mV
		$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$	–	–	6.5	mV
Input Offset Current			–	1.8	5.0	μA
		$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$	–	–	7.5	μA
Input Bias Current			–	16	25	μA
		$T_A = 0^{\circ}\text{C}$	–	25	40	μA
Voltage Gain			1000	1500	–	
		$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$	800	–	–	
Output Resistance			–	200	–	Ω
Output Sink Current	$\Delta V_{IN} \geq 5\text{mV}$, $V_{OUT} = 0$		1.6	2.5	–	mA
		$T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$	0.5	–	–	mA
Response Time	Note 2		–	40	–	ns
Average Temperature Coefficient of Input Offset Voltage	$R_S = 50\Omega$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		–	5.0	20	$\mu\text{V}/^{\circ}\text{C}$
Average Temperature Coefficient of Input Offset Current	$T_A = +25^{\circ} \text{ to } +70^{\circ}\text{C}$		–	15	50	$\text{nA}/^{\circ}\text{C}$
	$T_A = +25^{\circ} \text{ to } 0^{\circ}\text{C}$		–	24	100	$\text{nA}/^{\circ}\text{C}$
Input Voltage Range	$V = -7\text{V}$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		± 5	–	–	V
Common Mode Rejection Ratio	$R_A \leq 200\Omega$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		70	98	–	dB
Output HIGH Voltage	$\Delta V_{IN} \geq 5\text{mV}$, $0 \leq I_{OUT} \leq 5\text{mA}$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		2.5	3.2	4.0	V
Output LOW Voltage	$\Delta V_{IN} \geq 5\text{mV}$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		–1.0	–0.5	0	V
Output Sink Current	$\Delta V_{IN} \geq 5\text{mV}$, $V_{OUT} = 0$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		0.5	–	–	mA
Positive Supply Current	$V_{OUT} \leq 0$, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		–	5.2	9.0	mA
Negative Supply Current	$V_{OUT} = \text{GND}$, Inverting Input = 5mV, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		–	4.6	7.0	mA
Power Consumption	$V_{OUT} = \text{GND}$, Inverting Input = 10mV, $T_A = 0^{\circ} \text{ to } +70^{\circ}\text{C}$		–	90	150	mW

Note 1. The input offset voltage and input offset current are specified for a logic threshold voltage as follows: 1.5V at 0°C , 1.4V at $+25^{\circ}\text{C}$, and 1.2V at $+70^{\circ}\text{C}$.

Note 2. The response time specified is for a 100mV input step with 5mV overdrive.

Pin Connection Diagram

NTE910



NTE910D

